



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
	$14m\Omega @ V_{GS} = -20V$	-10A
-30V	18mΩ @ V _{GS} = -10V	-8.8A
	36mΩ @ V _{GS} = -4.5V	-6.2A

Description

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$, yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- Power Management Functions
- DC-DC Converters

SINGLE P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

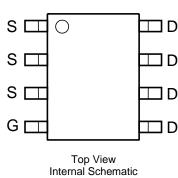
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

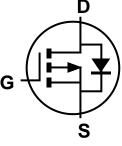
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (Approximate)



Top View



SO-8



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3035LSS-13	SO-8	2,500/Tape & Reel

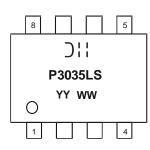
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



);; = Manufacturer's Marking P3035LS = Product Type Marking Code YYWW = Date Code Marking YY or YY = Year (ex: 13 = 2013) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-30	V
Gate-Source Voltage			V _{GSS}	±25	V
Drain Current (Note 5) (V _{GS} = -20V)	Steady State	T _A = +25°C T _A = +70°C	۱ _D	-10 -8	A
Pulsed Drain Current (Note 6)			I _{DM}	-80	A

Thermal Characteristics

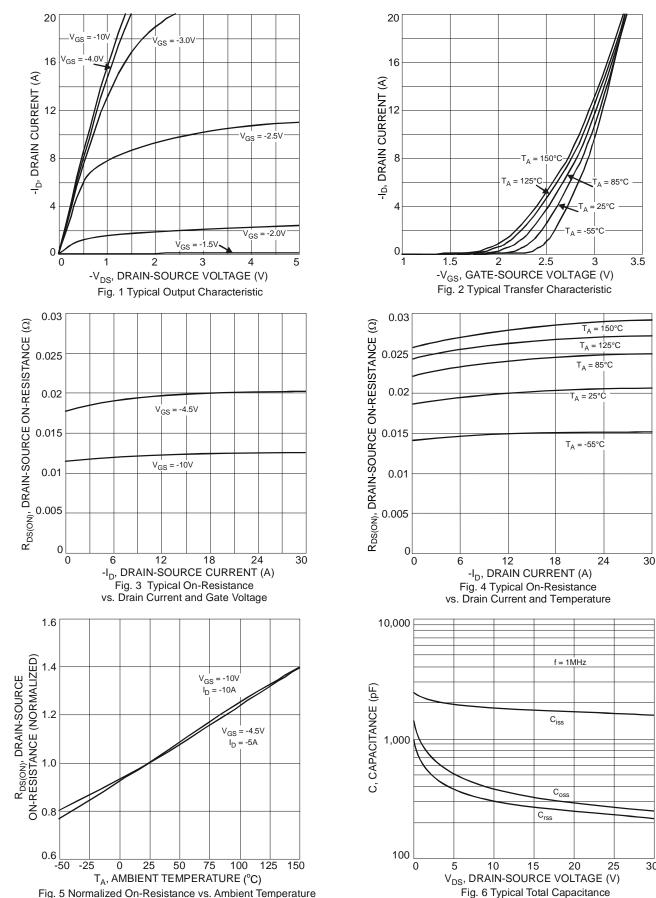
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	2.0	W
Thermal Resistance, Junction to Ambient	R _{θJA}	60	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	·	•			•	•
Drain-Source Breakdown Voltage	BV _{DSS}	-30		_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_		-1	μA	$V_{DS} = -30V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}			±100 ±800	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$ $V_{GS} = \pm 25V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)		•				•
Gate Threshold Voltage	V _{GS(TH)}	-1		-2	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
Static Drain-Source On-Resistance	R _{DS(ON)}		11 15 27	14 18 36	mΩ	$V_{GS} = -20V, I_D = -11A$ $V_{GS} = -10V, I_D = -8A$ $V_{GS} = -4.5V, I_D = -5A$
Forward Transconductance	G _{fs}		12	_	S	$V_{DS} = -10V, I_D = -12A$
Diode Forward Voltage (Note 7)	V _{SD}	-0.5	_	-1.1	V	$V_{GS} = 0V, I_{S} = -2A$
DYNAMIC CHARACTERISTICS	·					
Input Capacitance	C _{iss}		1,655		pF	V _{DS} = -20V, V _{GS} = 0V f = 1.0MHz
Output Capacitance	C _{oss}		286		pF	
Reverse Transfer Capacitance	C _{rss}	_	240	_	pF	
Gate Resistance	R _G	_	2.3	_	Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$
SWITCHING CHARACTERISTICS						
Total Gate Charge	Qg		15.3 30.7			$V_{DS} = -15V, V_{GS} = -4.5V, I_D = -8A$ $V_{DS} = -15V, V_{GS} = -10V, I_D = -8A$
Gate-Source Charge	Q _{gs}		3.5		nC	$V_{DS} = -15V, V_{GS} = -10V, I_D = -8A$
Gate-Drain Charge	Q _{gd}	—	7.9			$V_{DS} = -15V, V_{GS} = -10V, I_D = -8A$
Turn-On Delay Time	t _{D(ON)}		5.1	_		
Rise Time	t _R		8	_		V _{GS} = -10V, V _{DS} = -15V,
Turn-Off Delay Time	t _{D(OFF)}		46		ns	$R_D = 15\Omega, R_G = 6\Omega$
Fall Time	t _F		30]	

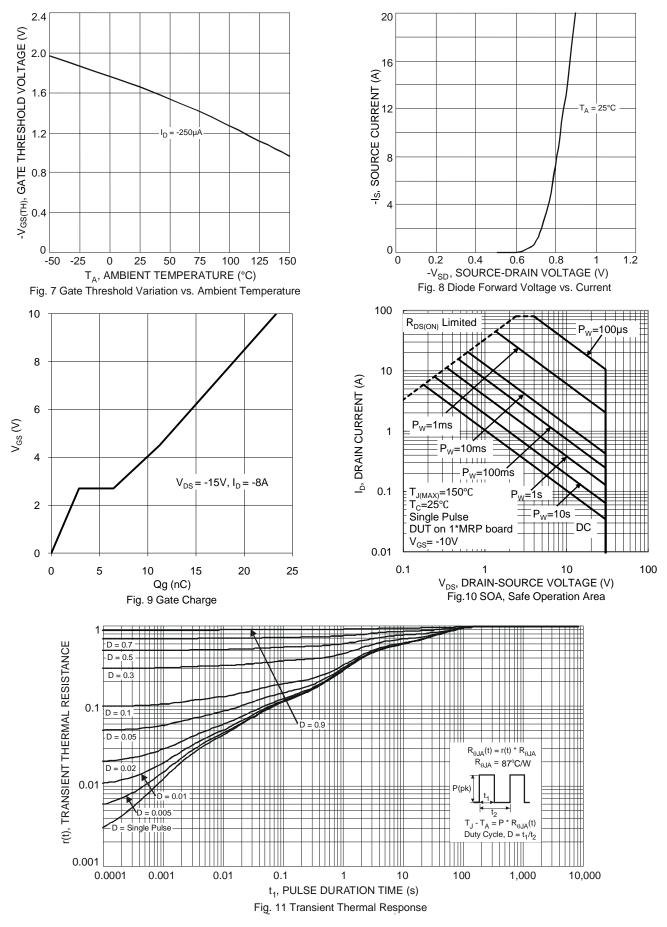
 Device mounted on 1 inch² FR-4 board with 2 oz. copper, in a still-air environment with T_A = +25°C.
 Repetitive rating, pulse width limited by junction temperature.
 Short duration pulse test used to minimize self-heating effect. Notes:





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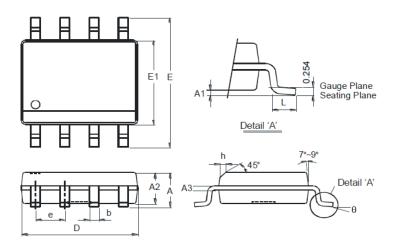




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

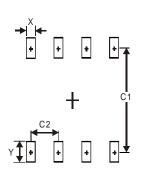
SO-8



SO-8				
Dim	Min	Max		
Α		1.75		
A1	0.10	0.20		
A2	1.30	1.50		
A3	0.15	0.25		
b	0.3	0.5		
D	4.85	4.95		
Е	5.90	6.10		
E1	3.85	3.95		
e	1.27 Typ			
h		0.35		
L	0.62	0.82		
θ	0°	8°		
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8

Dimensions	Value (in mm)			
Х	0.60			
Y	1.55			
C1	5.4			
C2	1.27			



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